

Trans IGBT Chip N-CH 1700V 6A 75mW 3-Pin(2+Tab) TO-268

Manufacturer:	Littelfuse Inc
Package/Case:	TO-268
Product Type:	Thyristors
Lifecycle:	Active





General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features	Application
High blocking voltage	Radar transmitter power supplies
High power density	Radar pulse modulators
High current handling capability	Capacitor discharge circuits
Low conduction losses	
MOS gate turn on for drive simplicity	High voltage power supplies
International standard and proprietary ISOPLUSTM packages	AC switches
Benefits:	HV circuit breakers
Eliminates multiple series-parallel lower voltage, lower current rateddevices	Pulser circuits
Simpler system design	High voltage test equipment
Improved reliability	881F
Reduced component count	Laser & X-ray generators
Reduced system cost	

Recommended For You

IXGH48N60C3D1	IXYX100
Littelfuse Inc	Littelfuse
TO-247	PLUS247
IXYN30N170CV1	IXBH16N
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IXGH48N60A3

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TO-247

IXGP20N120A3

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TO-220

IXGP8N100

Littelfuse Inc

TO-220

0N120C3

Inc

N170 Littelfuse Inc TO-247

IXGN320N60A3

Littelfuse Inc MODULE

IXYR50N120C3D1 Littelfuse Inc

ISOPLUS247

IXTQ460P2 Littelfuse Inc TO-3P

IXGH30N60B2D1

Littelfuse Inc TO-247

IXGH60N60C2 Littelfuse Inc TO-247

IXGH60N60C3

Littelfuse Inc TO-247

IXYH50N65C3D1

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IXGR48N60C3D1

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